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Kind regards,

Team Nexperia

PESD5V0V1BA; PESD5V0V1BB; PESD5V0V1BL

Very low capacitance bidirectional ESD protection diodes

Rev. 2 — 9 November 2012

Product data sheet

1. **Product profile**

1.1 General description

Very low capacitance bidirectional ElectroStatic Discharge (ESD) protection diodes in small Surface-Mounted Device (SMD) plastic packages designed to protect one signal line from the damage caused by ESD and other transients.

Table 1. **Product overview**

Type number	Package		Package configuration
	NXP	JEITA	
PESD5V0V1BA	SOD323	SC-76	very small
PESD5V0V1BB	SOD523	SC-79	ultra small and flat lead
PESD5V0V1BL	SOD882	-	leadless ultra small

1.2 Features and benefits

- Bidirectional ESD protection of one line ESD protection up to 30 kV
- Very low diode capacitance: C_d = 11 pF IEC 61000-4-2; level 4 (ESD)
- Max. peak pulse power: P_{PP} = 45 W
- Low clamping voltage: V_{CL} = 12.5 V
- Ultra low leakage current: I_{RM} < 1 nA</p>

1.3 Applications

- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories
- Subscriber Identity Module (SIM) card protection

1.4 Quick reference data

Table 2. **Quick reference data**

 $T_{amb} = 25 \ \circ C$ unless otherwise specified.

umo	1					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{RWM}	reverse standoff voltage		-	-	5	V
C _d	diode capacitance	$f = 1 \text{ MHz}; V_R = 0 \text{ V}$	-	11	13	pF



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- IEC 61000-4-5 (surge); I_{PP} = 4.8 A
- AEC-Q101 qualified
- Communication systems
- Portable electronics
- 10/100 Mbit/s Ethernet
- FireWire

Very low capacitance bidirectional ESD protection diodes

2. Pinning information

Table 3.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
PESD5V	V1BA; PESD5V0V1BB		
1	cathode (diode 1)	[1]	
2	cathode (diode 2)	1 001aab540	1 2 sym045
PESD5V0)V1BL		
1	cathode (diode 1)	[1]	
2	cathode (diode 2)	1 2 Transparent top view	1 2 sym045

[1] The marking bar indicates pin 1.

3. Ordering information

Table 4.Ordering information

Type number	Package	Package						
	Name	Description	Version					
PESD5V0V1BA	SC-76	plastic surface-mounted package; 2 leads	SOD323					
PESD5V0V1BB	SC-79	plastic surface-mounted package; 2 leads	SOD523					
PESD5V0V1BL	-	leadless ultra small plastic package; 2 terminals; body $1.0 \times 0.6 \times 0.5$ mm	SOD882					

4. Marking

Table 5.	Marking codes	
Type num	ber	Marking code
PESD5V0	V1BA	1K
PESD5V0	V1BB	Z9
PESD5V0	V1BL	X1

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
P _{PP}	peak pulse power	$t_{p} = 8/20 \ \mu s$	<u>[1]</u> _	45	W
I _{PP}	peak pulse current	$t_p = 8/20 \ \mu s$	<u>[1]</u> -	4.8	А

Very low capacitance bidirectional ESD protection diodes

Table 6. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device					
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.

Table 7. ESD maximum ratings

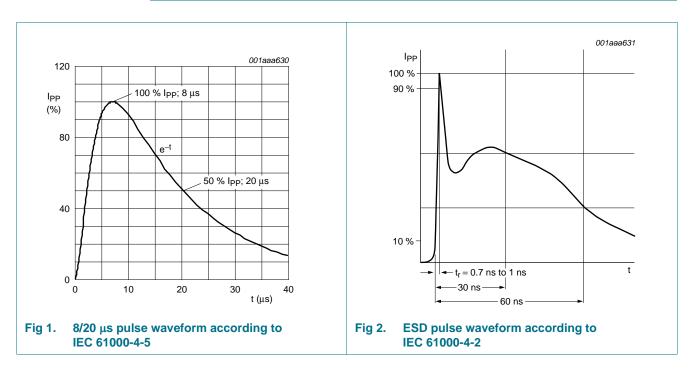
 $T_{amb} = 25 \ ^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions		Min	Max	Unit
V _{ESD} electrostatic discharge voltage	electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	[1]	-	30	kV
	machine model		-	2	kV	
		MIL-STD-883 (human body model)		-	16	kV

[1] Device stressed with ten non-repetitive ESD pulses.

Table 8. ESD standards compliance

Standard	Conditions
IEC 61000-4-2; level 4 (ESD)	> 15 kV (air); > 8 kV (contact)
MIL-STD-883; class 3B (human body model)	> 8 kV



PESD5V0V1BA_BB_BL

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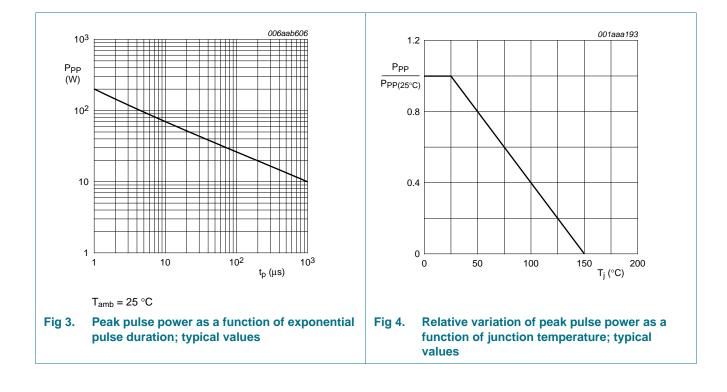
Very low capacitance bidirectional ESD protection diodes

6. Characteristics

Table 9. $T_{amb} = 25$	Characteristics ℃ unless otherwise specified.					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{RWM}	reverse standoff voltage		-	-	5	V
I _{RM}	reverse leakage current	$V_{RWM} = 5 V$	-	< 1	10	nA
V _{BR}	breakdown voltage	I _R = 5 mA	5.8	6.8	7.8	V
C _d	diode capacitance	f = 1 MHz; V _R = 0 V	-	11	13	pF
V _{CL}	clamping voltage	I _{PP} = 4.8 A	<u>[1]</u> -	-	12.5	V
r _{dyn}	dynamic resistance	I _R = 10 A	[2] _	0.2	-	Ω
r _{dif}	differential resistance	$I_R = 5 \text{ mA}$	-	-	35	Ω

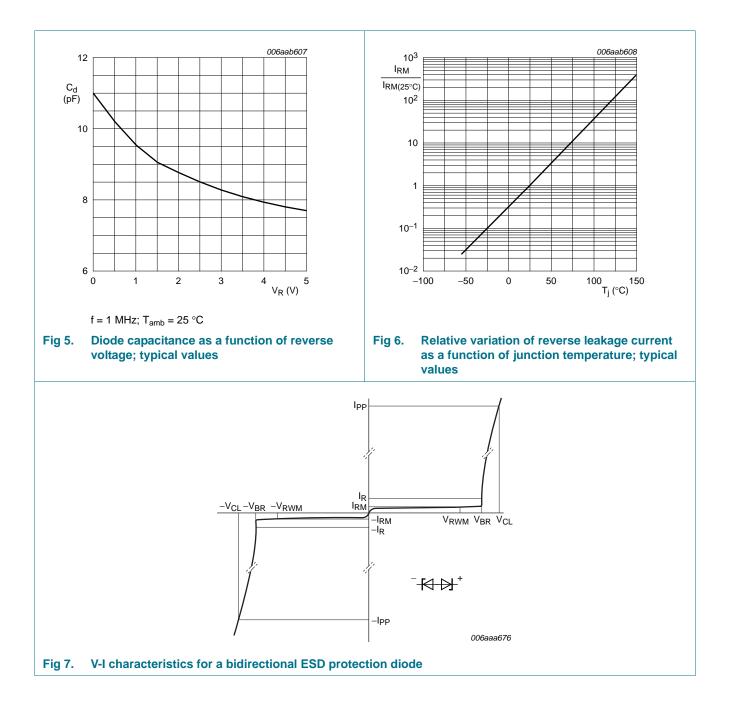
[1] Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.

[2] Non-repetitive current pulse, Transmission Line Pulse (TLP) t_p = 100 ns; square pulse; ANS/IESD STM5.1-2008.



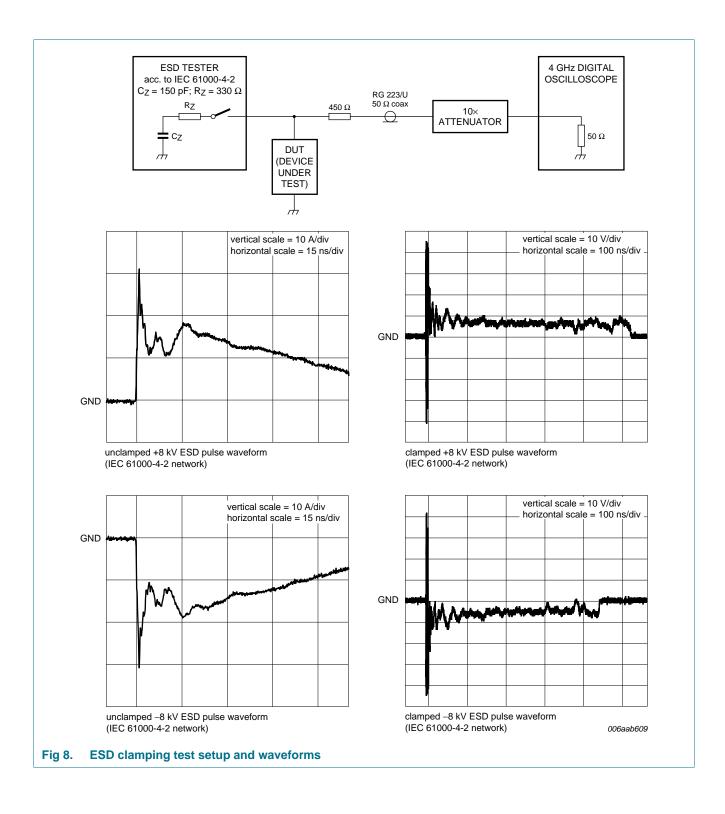
PESD5V0V1BA/BB/BL

Very low capacitance bidirectional ESD protection diodes



PESD5V0V1BA/BB/BL

Very low capacitance bidirectional ESD protection diodes

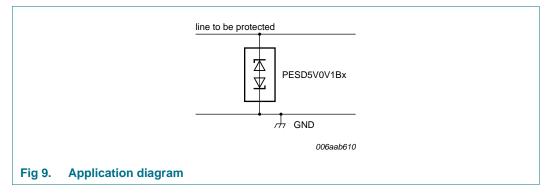


PESD5V0V1BA_BB_BL

Very low capacitance bidirectional ESD protection diodes

7. Application information

The PESD5V0V1Bx series is designed for the protection of one bidirectional data or signal line from the damage caused by ESD and surge pulses. The devices may be used on lines where the signal polarities are both, positive or negative with respect to ground. The PESD5V0V1Bx series provides a surge capability of 45 W per line for an 8/20 μ s waveform.



Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the device as close to the input terminal or connector as possible.
- 2. Minimize the path length between the device and the protected line.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Use ground planes whenever possible. For multilayer PCBs, use ground vias.

8. Test information

8.1 Quality information

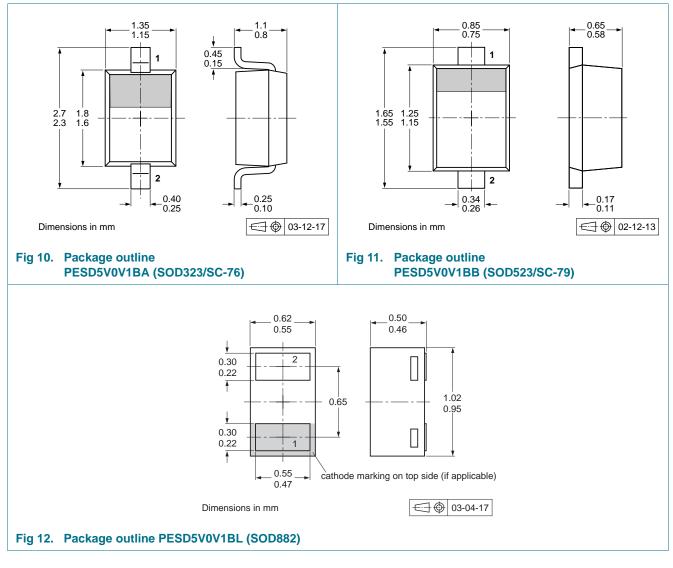
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

PESD5V0V1BA_BB_BL



Very low capacitance bidirectional ESD protection diodes

9. Package outline



10. Packing information

Table 10. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

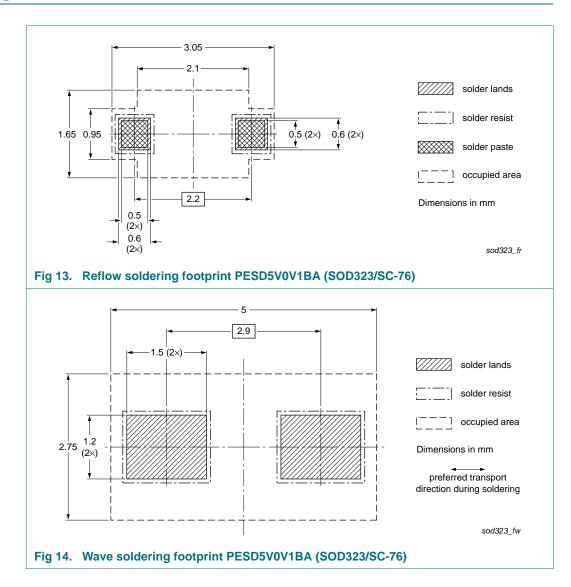
Type number	Package	Description	Packin	g quanti	ty
			3000	8000	10000
PESD5V0V1BA	SOD323	4 mm pitch, 8 mm tape and reel	-115	-	-135
PESD5V0V1BB	SOD523	2 mm pitch, 8 mm tape and reel	-	-315	-
		4 mm pitch, 8 mm tape and reel	-115	-	-135
PESD5V0V1BL	SOD882	2 mm pitch, 8 mm tape and reel	-	-	-315

[1] For further information and the availability of packing methods, see Section 14.

PESD5V0V1BA_BB_BL

Very low capacitance bidirectional ESD protection diodes

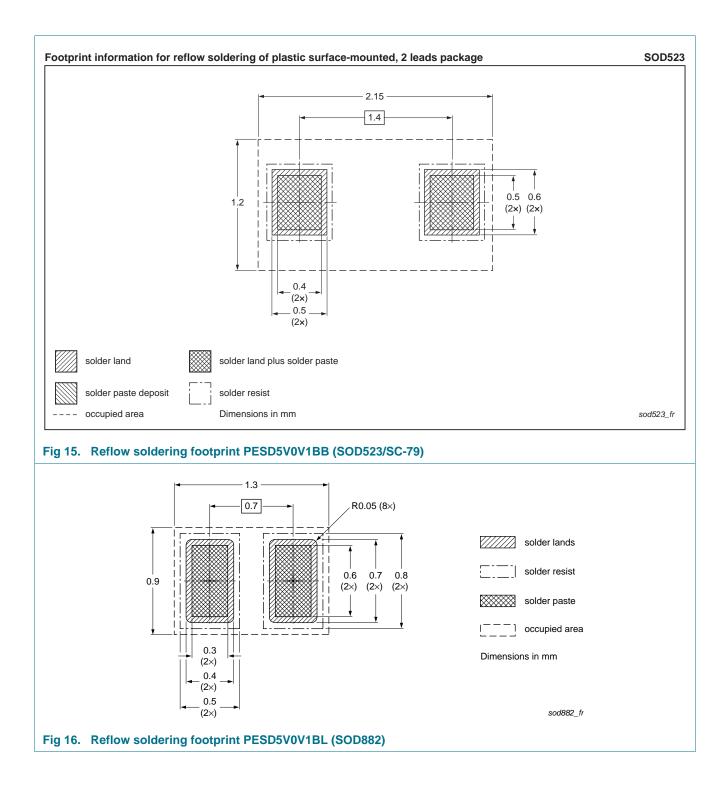
11. Soldering



PESD5V0V1BA_BB_BL

PESD5V0V1BA/BB/BL

Very low capacitance bidirectional ESD protection diodes



PESD5V0V1BA_BB_BL

Very low capacitance bidirectional ESD protection diodes

12. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
PESD5V0V1BA_BB_BL v.2	20121109	Product data sheet	-	PESD5V0V1BA_BB_BL v.1	
Modifications:	 <u>Table 9 "Characteristics"</u>: added dynamic resistance r_{dyn} <u>Time 15</u> 				
	 <u>Figure 15</u>: updated Section 13 "Legal information": updated 				
PESD5V0V1BA_BB_BL v.1	20090728	Product data sheet	-	-	

PESD5V0V1BA_BB_BL

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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PESD5V0V1BA/BB/BL

Very low capacitance bidirectional ESD protection diodes

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PESD5V0V1BA_BB_BL

Product data sheet

Very low capacitance bidirectional ESD protection diodes

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